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April 1<sup>st</sup>, 2010 Renesas Electronics Corporation

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# MOS FIELD EFFECT TRANSISTOR 2SK3483

# SWITCHING N-CHANNEL POWER MOS FET

### **DESCRIPTION**

The 2SK3483 is N-channel MOS Field Effect Transistor designed for high current switching applications.

### **FEATURES**

· Low on-state resistance

 $R_{DS(on)1}$  = 52  $m\Omega$  MAX. (Vgs = 10 V, Ip = 14 A)

RDS(on)2 = 59 m $\Omega$  MAX. (VGS = 4.5 V, ID = 14 A)

- Low Ciss: Ciss = 2300 pF TYP.
- Built-in gate protection diode
- TO-251/TO-252 package

### ORDERING INFORMATION

PART NUMBER	PACKAGE		
2SK3483	TO-251 (MP-3)		
2SK3483-Z	TO-252 (MP-3Z)		

# ABSOLUTE MAXIMUM RATINGS (TA = 25°C)

Drain to Source Voltage (Ves = 0V)	VDSS	100	V
Gate to Source Voltage (Vps = 0V)	Vgss	±20	V
Drain Current (DC)	I <sub>D(DC)</sub>	±28	Α
Drain Current (Pulse) Note1	ID(pulse)	±60	Α
Total Power Dissipation (Tc = 25°C)	Рт	40	W
Total Power Dissipation (T <sub>A</sub> = 25°C)	Рт	1.0	W
Channel Temperature	Tch	150	°C
Storage Temperature	Tstg	-55 to +150	°C
Single Avalanche Current Note2	las	25	Α
Single Avalanche Energy Note2	Eas	62.5	mJ

(TO-251)



(TO-252)



**Notes 1.** PW  $\leq$  10  $\mu$ s, Duty Cycle  $\leq$  1%

2. Starting T<sub>ch</sub> = 25°C, R<sub>G</sub> = 25  $\Omega$ , V<sub>GS</sub> = 20  $\rightarrow$  0 V

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# **ELECTRICAL CHARACTERISTICS (TA = 25°C)**

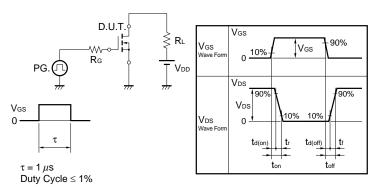
				i e		
CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	IDSS	V <sub>DS</sub> = 100 V, V <sub>GS</sub> = 0 V			10	μA
Gate Leakage Current	Igss	Vgs = ±20 V, Vps = 0 V			±10	μΑ
Gate Cut-off Voltage	V <sub>GS(off)</sub>	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 1 mA	1.5	2.0	2.5	V
Forward Transfer Admittance Note	y <sub>fs</sub>	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 14 A	9.0	18		S
Drain to Source On-state Resistance Note	RDS(on)1	Vgs = 10 V, Ip = 14 A		41	52	mΩ
	R <sub>DS(on)2</sub>	Vgs = 4.5 V, lp = 14 A		45	59	mΩ
Input Capacitance	Ciss	V <sub>DS</sub> = 10 V		2300		pF
Output Capacitance	Coss	Ves = 0 V		230		pF
Reverse Transfer Capacitance	Crss	f = 1 MHz		120		pF
Turn-on Delay Time	t <sub>d(on)</sub>	VDD = 50 V, ID = 14 A		12		ns
Rise Time	tr	Ves = 10 V		9		ns
Turn-off Delay Time	td(off)	$R_G = 0 \Omega$		53		ns
Fall Time	tf			5		ns
Total Gate Charge	Q <sub>G</sub>	VDD = 80 V		49		nC
Gate to Source Charge	Qgs	V <sub>G</sub> s = 10 V		7		nC
Gate to Drain Charge	Q <sub>GD</sub>	ID = 28 A	_	13		nC
Body Diode Forward Voltage Note	V <sub>F</sub> (S-D)	IF = 28 A, Vgs = 0 V		1.0		V
Reverse Recovery Time	trr	IF = 28 A, Vgs = 0 V		73		ns
Reverse Recovery Charge	Qrr	di/dt = 100 A/μs		175		nC

Note Pulsed

# **TEST CIRCUIT 1 AVALANCHE CAPABILITY**

# $V_{GS} = 20 \rightarrow 0 \text{ V}$ $V_{DD}$ $V_{DD}$

# TEST CIRCUIT 2 SWITCHING TIME

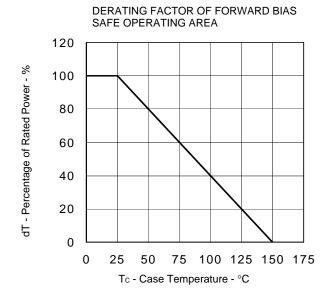


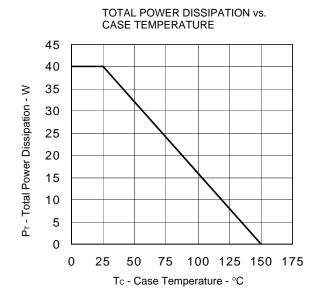
## **TEST CIRCUIT 3 GATE CHARGE**

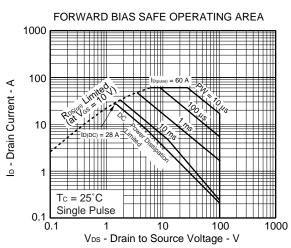
$$\begin{array}{c|c} D.U.T. \\ \hline \\ I_G = 2 \text{ mA} \\ \hline \\ \hline \\ V_{DD} \\ \hline \end{array}$$

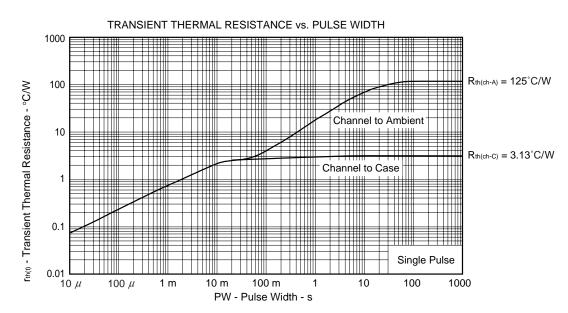


### TYPICAL CHARACTERISTICS (TA = 25°C)



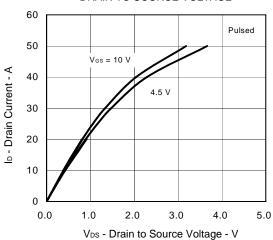




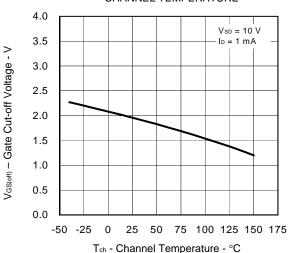


3

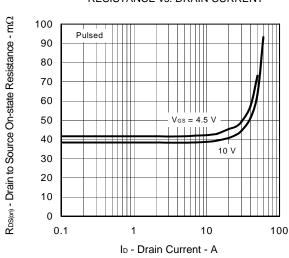
# DRAIN CURRENT vs. DRAIN TO SOURCE VOLTAGE



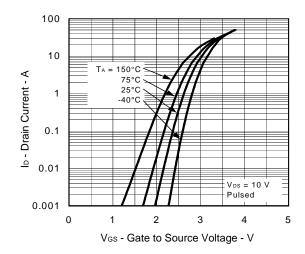
# GATE CUT-OFF VOLTAGE vs. CHANNEL TEMPERATURE



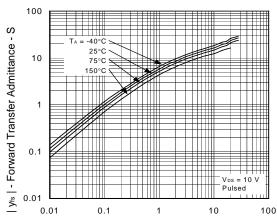
# DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT



### FORWARD TRANSFER CHARACTERISTICS

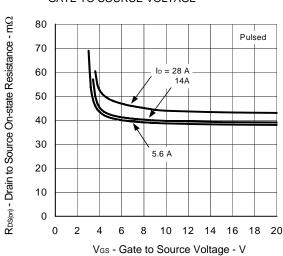


# FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT

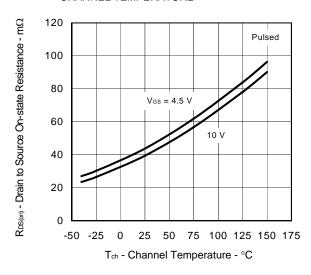


ID - Drain Current - A

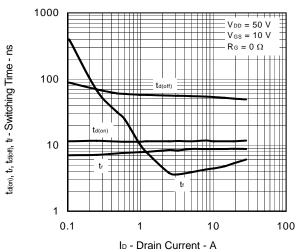
# DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE



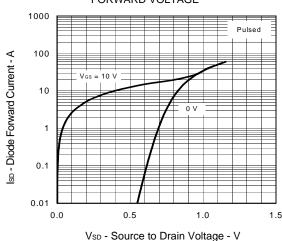
# DRAIN TO SOURCE ON-STATE RESISTANCE vs. CHANNEL TEMPERATURE



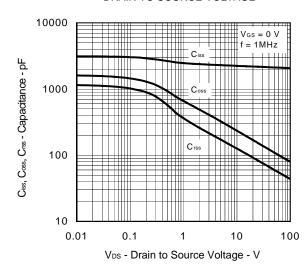
### SWITCHING CHARACTERISTICS



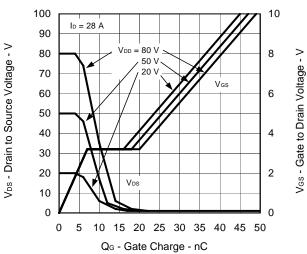
SOURCE TO DRAIN DIODE FORWARD VOLTAGE



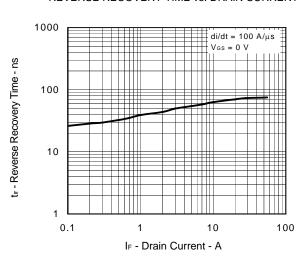
# CAPACITANCE vs. DRAIN TO SOURCE VOLTAGE



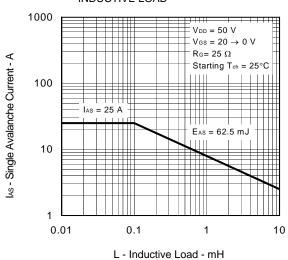
### DYNAMIC INPUT/OUTPUT CHARACTERISTICS



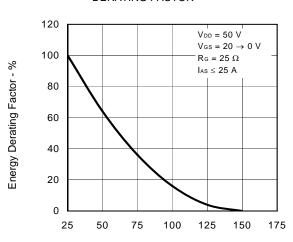
REVERSE RECOVERY TIME vs. DRAIN CURRENT



# SINGLE AVALANCHE CURRENT vs. INDUCTIVE LOAD



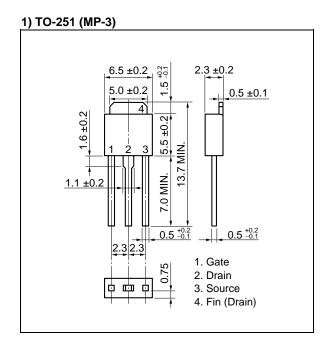
# SINGLE AVALANCHE ENERGY DERATING FACTOR



Starting T  $_{\text{ch}}$  - Starting Channel Temperature -  $^{\circ}\text{C}$ 



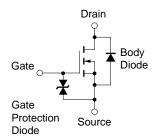
# **PACKAGE DRAWINGS (Unit: mm)**



# <R> 2) TO-252 (MP-3Z) 6.5 ±0.2 5.0 ±0.2 ŞĢ 2.3 ±0.2 4.4 ±0.2 -0.5 ±0.1 Note Note $5.6 \pm 0.3$ 5 ±0.5 -0.5 ±0.1 $0.5 \pm 0.1$ 2.3 ±0.3 2.3 ±0.3 0.15 ±0.15 1. Gate 2. Drain 3. Source 4. Fin (Drain)

**Note** The depth of notch at the top of the fin is from 0 to 0.2 mm.

## **EQUIVALENT CIRCUIT**



**Remark** The diode connected between the gate and source of the transistor serves as a protector against ESD.

When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

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